

M.Sc. 2nd Semester Examination, 2010

ELECTRONICS

(Semiconductor Devices)

PAPER—EL-1204

(Theory)

Full Marks : 40

Time : 2 hours

Answer Q. No. 1 and any three from the rest

The figures in the right-hand margin indicate marks

Candidates are required to give their answers in their own words as far as practicable

Illustrate the answers wherever necessary

1. Answer any five questions : 2 × 5

(a) What do you mean by the early effect in a transistor ?

(b) Discuss the function of a SCR as a variable half-wave rectifier.

(Turn Over)

(c) Why a power transistor cannot be used in high frequency operation ?

(d) Define the term threshold voltage of a junction field effect transistor. Write down its functional dependence on different device parameters.

(e) What is surface states pinning effect in a metal-semiconductor junction ?

(f) Distinguish between normal tunneling and resonant tunneling.

2. (a) Draw the circuit diagram of a CE amplifier using $n-p-n$ transistor also draw its output characteristics.

(b) Derive the expression of depletion layer width of a $p-n$ junction diode. Also, find the expression for depletion capacitance of the $p-n$ junction diode.

(2 + 2) + (4 + 2)

3. What do you mean by quasi-Fermi level ? Show that

$$pn = n_i^2 \exp \left\{ \frac{q(\phi_p - \phi_n)}{kT} \right\}$$

where ϕ_p and ϕ_n are quasi-Fermi levels for holes and electrons and other terms have their usual meanings. Derive expressions for the minority carrier concentrations on the two sides of a forward biased p - n junction as a function of bias voltage.

3 + 3 + 4

4. (a) What do you mean by the barrier height of a metal-semiconductor junction. For a metal-semiconductor junction prove that

$$\phi_{bp} + \phi_{bn} = E_g,$$

where the symbols have their usual meaning.

- (b) How can you determine the barrier height of a metal-semiconductor junction using activation energy method ?

(2 + 4) + 4

5. (a) What is an SCR ? Briefly explain its structure and characteristics. Can two transistors be connected to achieve the same effect ? Explain.

(b) What is so special about the SCR switch ? What is a Diac ? (1 + 2 + 2 + 2) + (2 + 1)

6. Draw the physical structure of a metal-semiconductor field effect transistor. Derive the current-voltage relation of the device under gradual channel approximation. 2 + 8

